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- Member of Texas Instruments' Widebus™ Family
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors

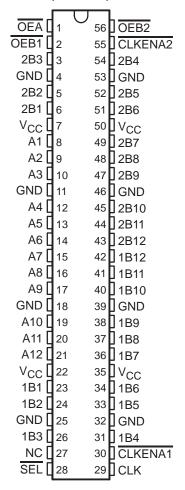
description

This 12-bit to 24-bit registered bus exchanger is designed for 1.65-V to 3.6-V V_{CC} operation.

The SN74ALVCH16269 is used in applications in which two separate ports must be multiplexed onto, or demultiplexed from, a single port. The device is particularly suitable as an interface between synchronous DRAMs and high-speed microprocessors.

Data is stored in the internal B-port registers on the low-to-high transition of the clock (CLK) input when the appropriate clock-enable (CLKENA) inputs are low. Proper control of these inputs allows two sequential 12-bit words to be presented as a 24-bit word on the B port. For data transfer in the B-to-A direction, a single storage register is provided. The select (SEL) line selects 1B or 2B data for the A outputs. The register on the A output permits the fastest possible data transfer, extending the period during which the data is valid on the bus. The control terminals are registered so that all transactions are synchronous with CLK. Data flow is controlled by the active-low output enables (OEA, OEB1, OEB2).

DGG OR DL PACKAGE (TOP VIEW)



NC - No internal connection

To ensure the high-impedance state during power up or power down, a clock pulse should be applied as soon as possible, and \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver. Due to \overline{OE} being routed through a register, the active state of the outputs cannot be determined before the arrival of the first clock pulse.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

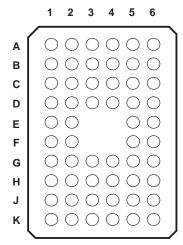
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SN74ALVCH16269 12-BIT TO 24-BIT REGISTERED BUS EXCHANGER WITH 3-STATE OUTPUTS

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GQL PACKAGE (TOP VIEW)



terminal assignments

	1	2	3	4	5	6
Α	2B3	OEB1	OEA	OEB2	CLKENA2	2B4
В	2B1	2B2	GND	GND	2B5	2B6
С	A2	A1	VCC	VCC	2B7	2B8
D	A4	А3	GND	GND	2B9	2B10
Е	A6	A5			2B11	2B12
F	A7	A8			1B11	1B12
G	A9	A10	GND	GND	1B9	1B10
Н	A11	A12	VCC	VCC	1B7	1B8
J	1B1	1B2	GND	GND	1B5	1B6
K	1B3	NC	SEL	CLK	CLKENA1	1B4

ORDERING INFORMATION

TA	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SSOP – DL	Tube	SN74ALVCH16269DL	ALVCH16269
-40°C to 85°C	330F - DL	Tape and reel	SN74ALVCH16269DLR	ALVCH16269
-40 C to 65 C	TSSOP – DGG	Tape and reel	SN74ALVCH16269DGGR	ALVCH16269
	VFBGA – GQL	Tape and reel	SN74ALVCH16269KR	VH269

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Function Tables

OUTPUT ENABLE

	INPUTS	OUTPUTS			
CLK	OEA	OEB	Α	1B, 2B	
1	Н	Н	Z	Z	
1	Н	L	Z	Active	
1	L	Н	Active	Z	
1	L	L	Active	Active	



A-TO-B STORAGE $(\overline{OEB} = L)$

	INPUTS						
CLKENA1	CLKENA2	CLK	Α	1B	2B		
L	Н	1	L	L	2B ₀ †		
L	Н	\uparrow	Н	Н	2B ₀ †		
L	L	\uparrow	L	L	L		
L	L	\uparrow	Н	Н	Н		
Н	L	\uparrow	L	1B ₀ †	L		
Н	L	\uparrow	Н	1B ₀ †	Н		
Н	Н	Χ	X	1B ₀ †	2B ₀ †		

[†]Output level before the indicated steady-state input conditions were established

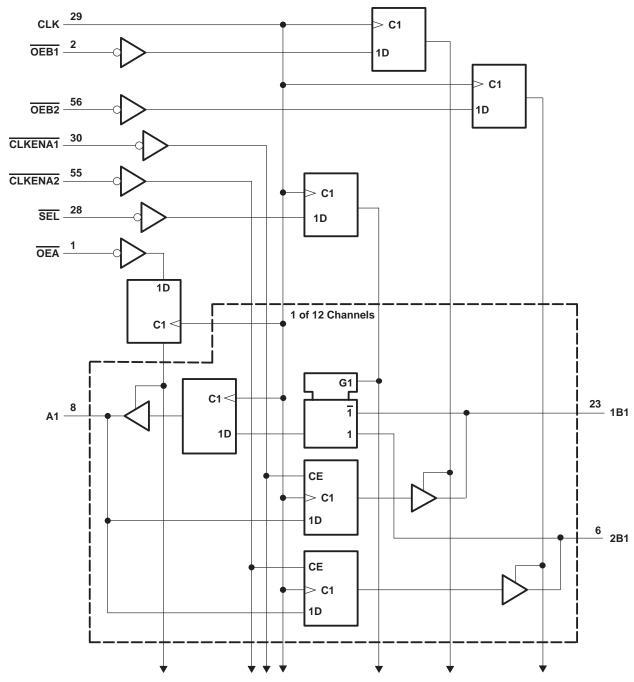
B-TO-A STORAGE (OEA = L)

	INP	OUTPUT		
CLK	SEL	1B	2B	Α
Х	Н	Χ	Χ	A ₀ †
Х	L	Χ	X	А _О Т А _О †
1	Н	L	X	L
1	Н	Н	X	Н
1	L	Χ	L	L
1	L	Χ	Н	Н

[†]Output level before the indicated steady-state input conditions were established

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logic diagram (positive logic)



Pin numbers shown are for the DGG and DL packages.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V _{CC}	
Input voltage range, V _I : Except I/O ports (see Note 1)	
I/O ports (see Notes 1 and 2)	
Output voltage range, VO (see Notes 1 and 2)	–0.5 V to V_{CC} + 0.5 V
Input clamp current, I _{IK} (V _I < 0)	–50 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Continuous output current, IO	
Continuous current through each V _{CC} or GND	±100 mA
Package thermal impedance, θ_{JA} (see Note 3): DGG package	81°C/W
DL package .	74°C/W
GQL package	28°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. This value is limited to 4.6 V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4)

			MIN	MAX	UNIT	
Vcc	Supply voltage		1.65	3.6	V	
		V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}			
V_{IH}	High-level input voltage	V _{CC} = 2.3 V to 2.7 V	1.7		V	
		V _{CC} = 2.7 V to 3.6 V	2			
		V _{CC} = 1.65 V to 1.95 V		0.35 × V _{CC}		
V_{IL}	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8		
VI	Input voltage		0	Vcc	V	
٧o	Output voltage		0	Vcc	V	
		V _{CC} = 1.65 V		-4		
la	High lovel output ourront	V _{CC} = 2.3 V		-12	mA	
ЮН	High-level output current	V _{CC} = 2.7 V		-12	IIIA	
		V _{CC} = 3 V		-24		
		V _{CC} = 1.65 V		4		
la.	Low lovel output ourrent	V _{CC} = 2.3 V		12		
IOL	Low-level output current	V _{CC} = 2.7 V		12	mA	
	V _{CC} = 3 V			24	1	
Δt/Δν	Input transition rise or fall rate	-		10	ns/V	
TA	Operating free-air temperature		-40	85	°C	

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PAI	RAMETER	TEST C	ONDITIONS	VCC	MIN	TYP [†]	MAX	UNIT
		I _{OH} = -100 μA		1.65 V to 3.6 V	V _{CC} -0.	2		
		I _{OH} = -4 mA		1.65 V	1.2			
		I _{OH} = -6 mA	2.3 V	2				
Vон				2.3 V	1.7			V
		I _{OH} = -12 mA		2.7 V	2.2			
				3 V	2.4			
		I _{OH} = -24 mA		3 V	2			
		I _{OL} = 100 μA		1.65 V to 3.6 V			0.2	
		I _{OL} = 4 mA		1.65 V			0.45	
VOL		I _{OL} = 6 mA		2.3 V			0.4	V
VOL		I _{OL} = 12 mA	2.3 V			0.7	v	
		IOL = 12 IIIA		2.7 V			0.4	
		I _{OL} = 24 mA	3 V			0.55		
lį		$V_I = V_{CC}$ or GND		3.6 V			±5	μΑ
		V _I = 0.58 V		1.65 V	25			
		V _I = 1.07 V		1.65 V	-25			
		V _I = 0.7 V		2.3 V	45			
I _{I(hold)}		V _I = 1.7 V		2.3 V	-45			μΑ
		V _I = 0.8 V		3 V	75			
		V _I = 2 V		3 V	-75			
		$V_{I} = 0 \text{ to } 3.6 \text{ V}^{\ddagger}$		3.6 V			±500	
loz§		$V_O = V_{CC}$ or GND		3.6 V			±10	μΑ
ICC		$V_I = V_{CC}$ or GND,	IO = 0	3.6 V			40	μΑ
∆ICC		One input at V _{CC} – 0.6 V,	Other inputs at V _{CC} or GND	3 V to 3.6 V			750	μΑ
Ci	Control inputs	$V_I = V_{CC}$ or GND		3.3 V		3.5		pF
Cio	A or B ports	$V_O = V_{CC}$ or GND		3.3 V		9		pF

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[‡] This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

[§] For I/O ports, the parameter IOZ includes the input leakage current.

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timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

			VCC =	1.8 V	V _{CC} =		VCC =	2.7 V	V _{CC} =		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
fclock	f _{clock} Clock frequency			†		135		135		135	MHz
t _W	Pulse duration	on, CLK high or low	†		3.3		3.3		3.3		ns
		A data before CLK↑	†		2		2		1.7		
	Setup time	B data before CLK↑	†		2.2		2.1		1.8		
t _{su}		SEL before CLK↑	†		1.6		1.6		1.3		ns
		CLKENA1 or CLKENA2 before CLK↑	†		1		1.2		0.9		
		OE before CLK↑	†		1.5		1.6		1.3		
		A data after CLK↑	†		0.7		0.6		0.6		
		B data after CLK↑	†		0.7		0.6		0.6		
th	Hold time	SEL after CLK↑	†		1.1		0.7		0.7		ns
		CLKENA1 or CLKENA2 after CLK↑	†		1		0.8		1.1		
		OE after CLK↑	†		0.8		0.8		0.8		

[†] This information was not available at the time of publication.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

PARAMETER FROM (INPUT)		TO V _{CC} = 1.8 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		UNIT	
	(INFOT)	(001701)	MIN	TYP	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}			†		135		135		135		MHz
	CLK	В		†	1	8.2		7.3	1	6.2	ns
^t pd	CLK	Α		†	1	6.4		5.8	1	5	115
	CLK	В		†	1	7.9		6.7	1	6.1	20
t _{en}	CLK	Α		†	1	7.6		6.2	1	5.9	ns
	CLK	В		†	1	8.1		6.9	1	6.1	20
^t dis		А		†	1	7.5		6.8	1	5.6	ns

[†] This information was not available at the time of publication.

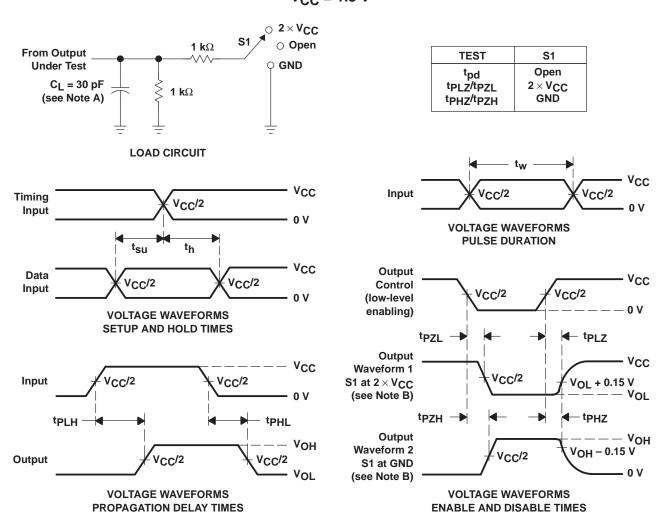
operating characteristics, T_A = 25°C

	PARAMETER		TEST CONDITIONS	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	UNIT
	Power dissipation	All outputs enabled	C ₁ = 50 pF. f = 10 MHz	†	87	120	pF
Cpd	capacitance per exchanger	All outputs disabled	$C_L = 50 \text{ pF}, f = 10 \text{ MHz}$	†	80.5	118	рг

[†] This information was not available at the time of publication.



PARAMETER MEASUREMENT INFORMATION V_{CC} = 1.8 V



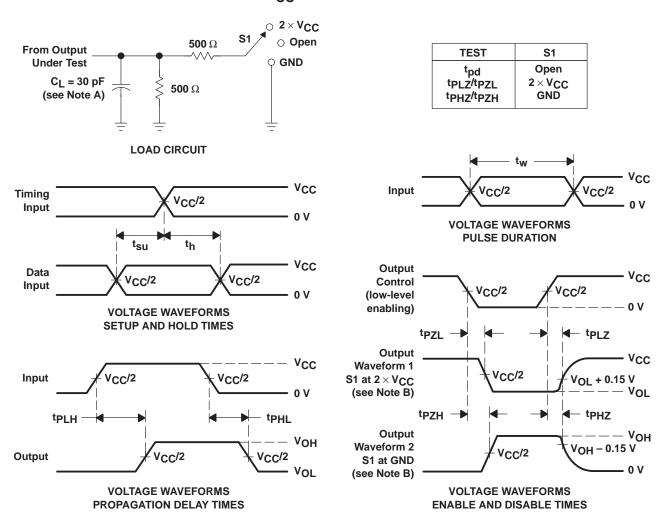
NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \Omega$, $t_f \leq$ 2 ns, $t_f \leq$ 2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$

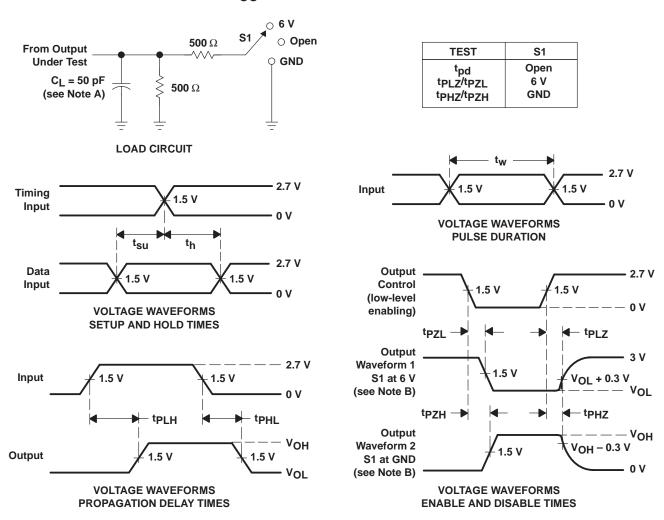


NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq 2$ ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION V_{CC} = 2.7 V AND 3.3 V \pm 0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \Omega$, $t_f \leq 2.5 \text{ ns.}$
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpl 7 and tpH7 are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 3. Load Circuit and Voltage Waveforms



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